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Atomic-Scale Control of Electron Transport through Single Molecules

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Tin-phthalocyanine molecules adsorbed on Ag(111) were contacted with a tip of a cryogenic scanning tunneling microscope. Orders-of-magnitude variations of the single-molecule junction conductance were obtained by controllably dehydrogenating the molecule and by modifying the atomic structures of the surface electrode. Nonequilibrium Green’s function calculations reproduce the trend of the conductance and visualize the current flow through the junction, which is guided through molecule-electrode chemical bonds.

The transport of electrons through molecules is relevant for many branches of science and important for potential applications in electrical engineering [1–11]. While the importance of atomic structure and bonding for transport through single-molecule junctions has repeatedly been emphasized, investigations with atomic-scale control of the junction geometry are scarce. Recent scanning tunneling microscope (STM) experiments have provided structural information about the electrodes and the orientation of contacted molecules with atomic precision [12–16]. This opens an avenue for controlling the current flow through single molecules by combining transport measurements with the atomic manipulation capabilities of a STM.

Here, we present STM measurements of the conductance of tin-phthalocyanine (SnPc) adsorbed on a Ag(111) surface and contacted by a Ag-covered W tip. By systematically manipulating the atomic bonding between SnPc and Ag(111) through selective dehydrogenation of SnPc together with an atomic-scale structuring of the Ag(111) electrode, the conductance of single-molecule junctions was controllably varied from 0.013 to 0.32G0 (G0 = 2e2/h, where e is electron charge and h is Planck’s constant). Ab initio calculations using density functional methods and nonequilibrium Green’s function techniques [17,18] enable a quantitative analysis of electron transport through Ag-SnPc-Ag junctions and a visualization of the guided current flow.

Experiments were performed with a homemade STM operated at 7 K and in ultrahigh vacuum with a base pressure of 10−9 Pa. Ag(111) and W tips were cleaned by Ar+ bombardment and annealing. Molecules were evaporated from a heated crucible and deposited onto the sample surface at room temperature. Single Ag atoms, which were used to structure the surface electrode by tip manipulation, had been transferred from the tip by controlled tip-surface contacts [19].

The leftmost images of Figs. 1(a) and 1(b) show that SnPc exhibits two configurations upon adsorption on Ag(111) [20]: configurations with central protrusions (depressions) in constant-current STM images correspond to molecules with their central Sn atom pointing towards vacuum (the surface) and are referred to as SnPc-up (SnPc-down) in the following. Both SnPc configurations may be easily dehydrogenated by placing the STM tip above a ligand and applying a voltage pulse. As a result, the two peripheral H atoms were dissociated from the isoindole ring as reported for CoPc on Au(111) [21]. A sequence of STM images of dehydrogenated SnPc molecules together with sketches of the calculated relaxed molecule structure are presented in Figs. 1(a) and 1(b). Ligands whose outer H atoms have been removed appear shorter than their intact counterparts. As shown by STM images and density functional calculations, for SnPc-up and SnPc-down dehydrogenation induces a marked change of the molecular structure. After removing H atoms, the dehydrogenated ligand bends towards the Ag(111) surface and forms a chemical bond between two unsaturated C atoms and Ag(111). The smallest C-Ag separation appearing in the calculations of the relaxed binding geometry is ≈2 Å, which leads to a much stronger binding of the molecule to Ag(111) than in the intact configuration.

In a first step the conductance of intact and dehydrogenated molecules was measured. To this end the tip was approached toward the Sn ion at a speed of 45 Å s−1 and the conductance was simultaneously recorded. Figure 2(a) presents experimental results for SnPc-up and its dehydrogenated products. The displacement axis shows the tip excursion towards the molecule with zero displacement corresponding to the position of the tip before opening the feedback loop of the microscope. The conductance increases exponentially in the tunneling region and corresponds to an apparent barrier height of 4.3 eV, which is slightly larger than the work function of clean Ag(111). At a conductance of =0.005G0, the slope of the conductance decreases.

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trace increases abruptly, which signals the transition to the contact region. The contact conductance $G_c$ is defined by the intersection of linear fits to the transition and the contact regions as illustrated by the solid lines in Fig. 2(a) and introduced in Refs. [14,15]. For SnPc-up a contact conductance of $G_c = 0.052 G_0$ is obtained in this way. SnPc-up molecules, from which two H atoms were removed (SnPc-up-2H), exhibit similar conductance curves, albeit with a slightly higher contact conductance of $G_c = 0.068 G_0$. Starting from SnPc-up-4H, the transition from tunneling to contact occurs with an appreciably lower slope and the contact conductances become smaller with increasing degree of dehydrogenation (SnPc-up-4H, $G_c = 0.020 G_0$; SnPc-up-6H, $G_c = 0.018 G_0$; SnPc-up-8H, $G_c = 0.013 G_0$).

A similar trend of the conductance evolution with increasing number of removed H atoms is observed for SnPc-down [Fig. 2(b)]. However, the conductances are considerably higher than for SnPc-up.

To understand the trends of conductance evolution with dehydrogenation, first-principles simulations (SIESTA [18]) and subsequent transport calculations (TRANSIESTA [17]) were performed. The unit cell for transport calculations consists of 509 atoms comprising 56 atoms per Ag layer (4 layers for the substrate and for the tip), 4 atoms for the pyramidal tip, and 57 atoms for the intact molecule. The geometry was optimized by minimizing the molecular and tip forces in a smaller cell having two or three Ag layers. The calculations model the experimental findings in a qualitative way. Deviations are most likely due to van der Waals forces, which influence the junction geometry and are not properly accounted for in density functional theory. Calculated contact conductances were therefore evaluated at fixed tip-Sn distances (3.0 Å for SnPc-up-$n$H, 4.0 Å for Sn-Pc-down-$n$H junctions), which were extracted from simulated conductance curves showing a clear transition between tunneling and contact. While the calculated conductances scale with the tip-Sn distance, the trends depicted in Figs. 2(c) and 2(d) are not affected significantly.

Individual transport channels were calculated to find the contributions of the Sn atom, the $\pi$ molecular orbitals, and the C-Ag chemical bonds between the (dehydrogenated) molecule and Ag(111) to the total conductance at contact [22]. For the SnPc-up series, the transmission is dominated by the $\pi$ orbitals, which on Ag(111) are located slightly above the Fermi level [Fig. 2(c)], and which originate from the degenerate lowest unoccupied molecular orbital [23]. Upon dehydrogenation C-Ag chemical bonds are formed, which leads to a bending of the molecule and a concomitant lifting of the central Sn ion from the surface. Together with the mechanical distortion of the molecule, the modification of its $\pi$ electronic system gives rise to a shift of the transmission peak away from the Fermi level [Fig. 2(c)], which in turn leads to a decrease of contact conductances of the dehydrogenated SnPc products. In particular, SnPc-up-8H exhibits a highly distorted molecular plane with Sn lifted away from the surface by 1.0 Å compared to the intact molecule. This molecule further shows the lowest contact conductance. The stronger chemical bonding of dehydrogenated molecules may explain the smooth transition to contact observed from SnPc-up-4H, -6H, -8H since the resulting relaxations of the
molecule are reduced. SnPc-up and SnPc-up-2H, which are more weakly bonded to the surface, exhibit a rather abrupt tunneling-to-contact transition. A similar behavior was reported for adsorbed Ag and Cu atoms [19]. The different chemical bondings may also explain the local maxima observed in conductance curves of SnPc-up-nH (n = 0, 2, 4, 6, 8). The conductance curves have been horizontally shifted for clarity (2H, −0.8 Å; 4H, −0.2 Å; 6H, 0.4 Å; 8H, −0.4 Å). (b) Like (a) for SnPc-down-nH (2H, −0.2 Å; 4H, −0.5 Å; 6H, 0.8 Å; 8H, −0.8 Å). Zero displacement is defined by feedback loop parameters of 0.1 V, 10 nA. Solid lines in (a) are linear fits to the transition region and a part of the contact region. The intersection of these fits defines the contact conductance, which is indicated by stars for all other curves. (c) Calculated energy of the transmission maximum as a function of n (Fermi energy is set to zero). (d) Comparison of experimental (red) and calculated (blue) contact conductances ($G_c$) of SnPc-down (squares) and SnPc-up (circles).

Based on the above analysis, a decrease of the conductance at contact of the SnPc-down series is also determined by the $\pi$ orbitals, with an additional contribution of the Sn atom owing to its binding to Ag(111). The most conducting channel is responsible for ≈70% of the total transmission, while this figure is ≈30% for the next most conducting channel. Both channels show $\pi$ character and have a significant weight on the Sn atom. Consequently, SnPc-down exhibits a higher conductance than SnPc-up. Similar to the SnPc-up series, progressive dehydrogenation gives rise to a continued decrease of contact conductance. For SnPc-down-8H the strong molecular deformation lifts the Sn atom by 0.7 Å from the Ag(111) surface compared to the intact molecule and its coupling to the substrate is efficiently reduced.

These results show that by modifying the chemical bonding between molecule and surface the conductance of the molecular junction may be tuned in a controlled way. To obtain the current pathway from molecule to surface, all local currents flowing in the bonds between individual atoms in the molecule and all atoms in the surface are summed up [24–26]. Since almost the entire current flow from tip to surface is via the molecule, these individual currents for each atom in the molecule add up to the total current. Therefore, the contribution to the total current of each atom or group of atoms in the molecule and the Ag(111) surface was evaluated and is shown in the bar charts in Figs. 3(a) and 3(b) for SnPc-down and SnPc-down-8H. First, ≈60% of the total current between molecule and surface flow through the outermost C atoms ($C_o$) for the intact molecule, while ≈97% of the total current flow between these directly surface-bonded C atoms for the dehydrogenated molecule. Thus, the outermost C atoms of the molecule appear to play a particularly important role in electron transport through the molecule. Second, the current in the bonds between the central Sn atom and the surface contributes ≈43% for the intact SnPc-down molecule, while it is reduced to ≈16% for SnPc-down-8H. In other words, electron transport through a channel containing the Sn atom is strongly reduced upon removing the outermost H atoms. The current pathway through other chemical bonds between C, N, H atoms and the surface are seen to be of minor importance. Negative bond currents are directed opposite to the total current and reflect quantum interferences, which can lead to loop currents [26].
at the C-Ag bonds [27]. To test this hypothesis further, the flat adsorption geometry of SnPc on Ag(111) was modified by moving the molecule onto Ag clusters of different sizes, which had been fabricated by atom manipulation before. As shown by STM images and sketches of the relaxed adsorption geometries [Fig. 1(c)], this atomic-scale structuring of the Ag(111) electrode causes a partial lifting of SnPc molecules from the Ag(111) surface. The degree of detaching the molecule from the surface may be controlled to some extent by the choice of the cluster size and by its position below the molecule plane. A SnPc-up molecule is weakly lifted from the Ag(111) surface when a single Ag atom is located between two adjacent ligands close to one N atom [Fig. 2(c), AgSnPc-up] and its contact conductance, $G = 0.058 G_0$, is slightly modified compared to the flat adsorption [Fig. 1(a)]. A $\text{Ag}_2$ cluster positioned below a ligand of SnPc-up ($\text{Ag}_2\text{SnPc}$-up), two $\text{Ag}_2$ clusters below two neighboring ligands ($\text{Ag}_2\text{Ag}_2\text{SnPc}$-up), and a $\text{Ag}_4$ cluster below a single ligand ($\text{Ag}_4\text{SnPc}$-up) progressively detach the molecule from the surface. A SnPc-up molecule supported by a Ag dimer or a Ag tetramer exhibits contact conductances of $0.025 G_0$ and $0.019 G_0$, which are lower by 50% and 70% compared to the values obtained for the flat molecule. The contact conductance slightly increased to $0.030 G_0$ for $\text{Ag}_2\text{Ag}_2\text{SnPc}$-up, which may originate from an increased contact area between the molecule and the electrode. For $\text{Ag}_4\text{SnPc}$-down, the contact conductance drops by 80% to $0.054 G_0$ compared to SnPc-down because of the decreased $\pi$-surface and Sn-surface coupling.

In summary, pathways of the electron current through a molecular junction were investigated using STM-based transport and manipulation experiments along with calculations. Control of the conductance and guiding of the electron current were achieved by modifying the chemical interaction of the molecule with the electrodes and by atomic-scale structuring the electrodes. This approach may be extended to electron transfer processes for a wide range of molecular junctions.

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